

CMOS Active Transformers and Applications

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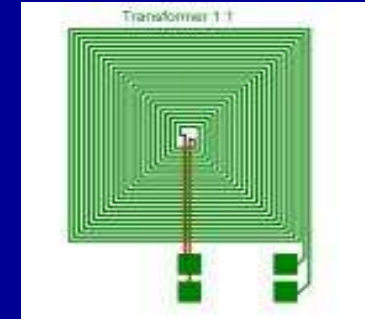
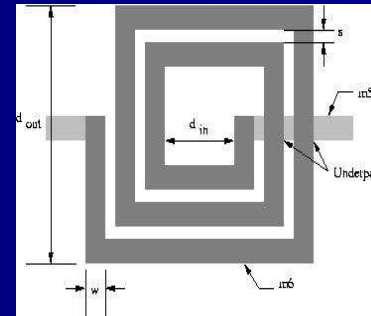
Outline

- Spiral/MEMS inductors and transformers
- Active inductors
- Ideal active transformers
- Non-ideal active transformers
- Active transformers with multiple windings
- Implementation of active transformers
- Applications of active transformers
- Conclusions
- References

Spiral inductors / transformers

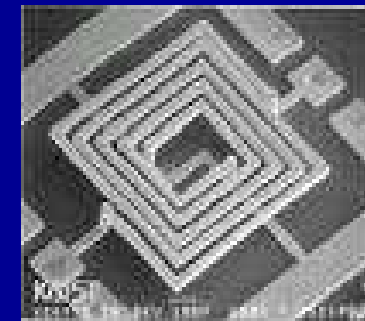
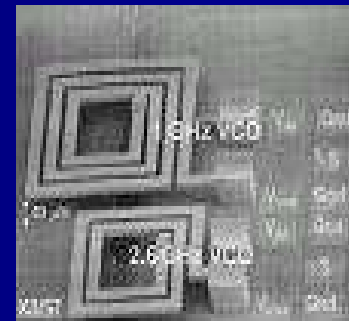
■ Spiral inductors / transformers

- Superior linearity
- Excellent noise performance
- Large L with stacked spirals
- Extremely silicon consuming
- Non-tunable inductances and coupling factors
- Low Q (typically $Q < 20$)
- Cannot realized using digital CMOS processes.



■ MEMS inductors/transformers

- Excellent performance (Q and noise).
- Tunable inductances
- Expensive – require monolithic CMOS-MEMS processes
- Extremely silicon consuming



Active inductors

- Gyration-C configuration exhibits an inductive characteristic in a specific frequency range.

$$R_p = \frac{1}{g_{o2}}, C_p = C_2, R_s = \frac{g_{o1}}{g_{m1}g_{m2}}, L = \frac{C_1}{g_{m1}g_{m2}}.$$

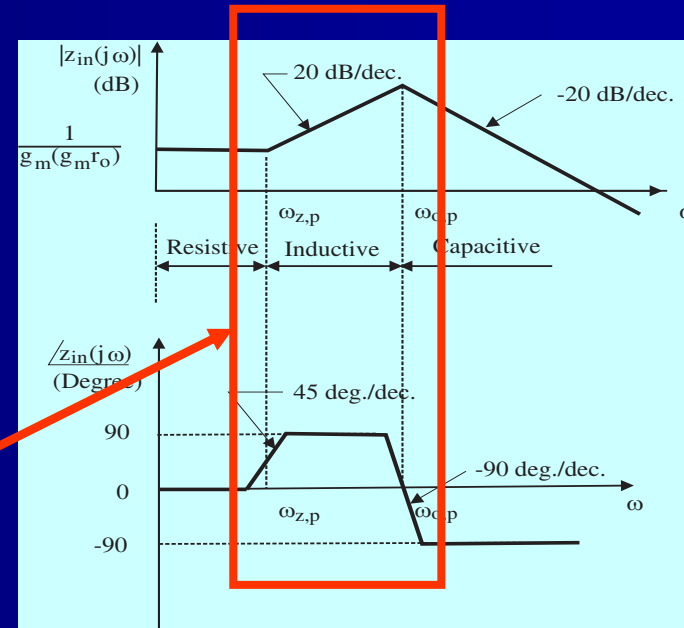
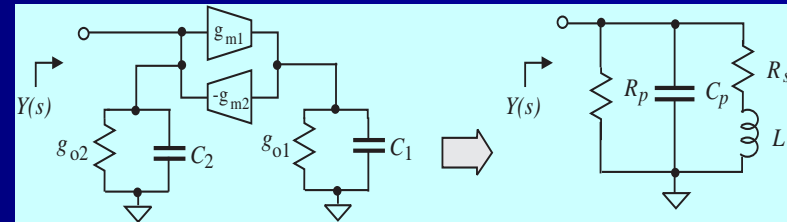
- Frequency range

$$\omega_z = \frac{g_o}{C} < \omega < \omega_p = \frac{g_m}{C}$$

- To maximize frequency range

- Upper bound set by the cut-off frequency of transconductors
- Transconductors
 - Generic transconductors
- Capacitors
 - Device intrinsic capacitances

Inductive



Active inductors (cont'd)

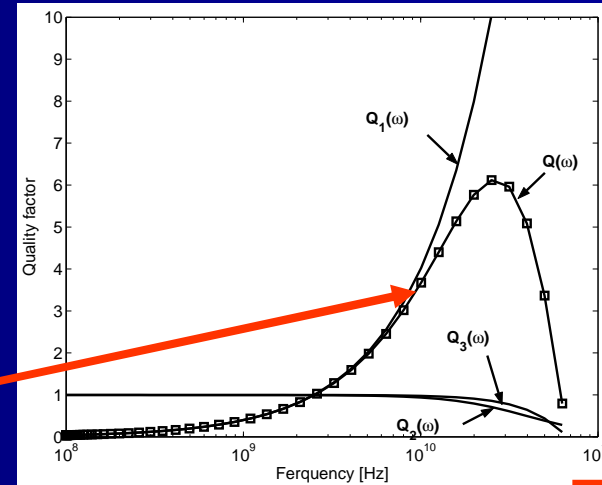
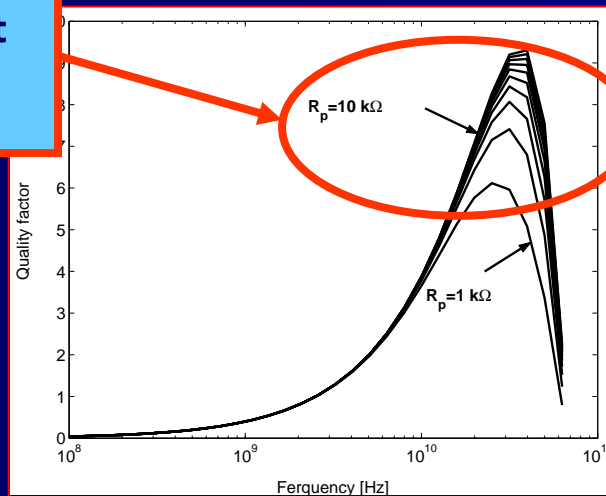
Quality factor

$$Q = \left(\frac{\omega L}{R_s} \right) \frac{R_p}{R_p + R_s} \left[1 + \left(\frac{\omega L}{R_s} \right)^2 \right] \left[1 - \frac{R_s^2 C_p}{L} - \omega^2 L C_p \right]$$

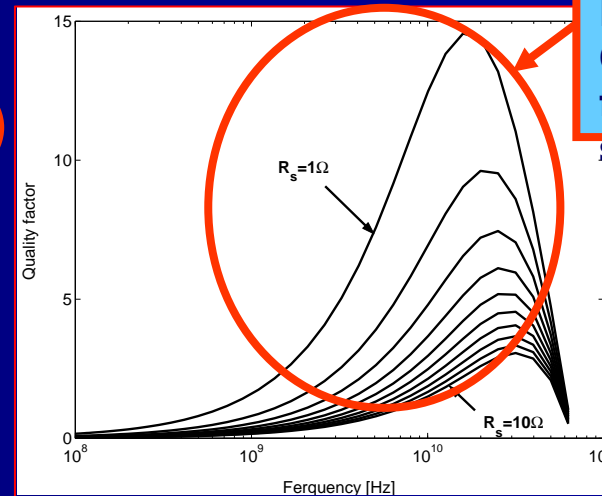
$$= Q_1 Q_2 Q_3$$

Q is dominated by $Q_1 = \frac{\omega L}{R_s}$ at low frequencies. Reducing R_s is critical.

R_p affects Q at high frequencies



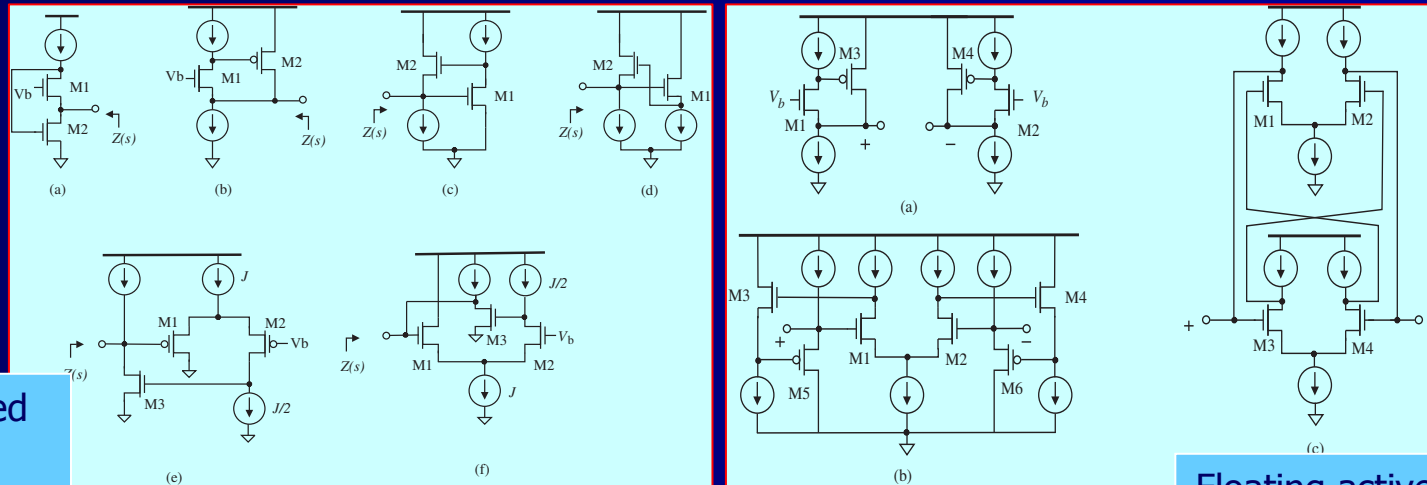
R_s affects Q at low frequency



Q increases as R_s decreases

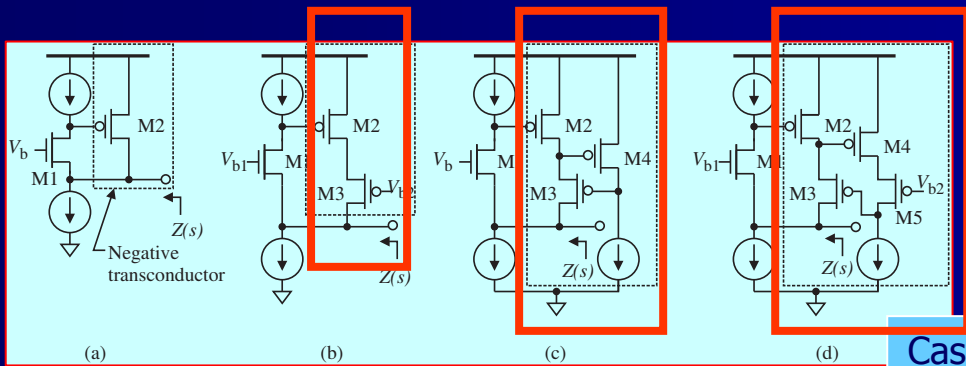
Active inductors (cont'd)

Implementation of CMOS active Inductors



Grounded active inductors

Floating active inductors

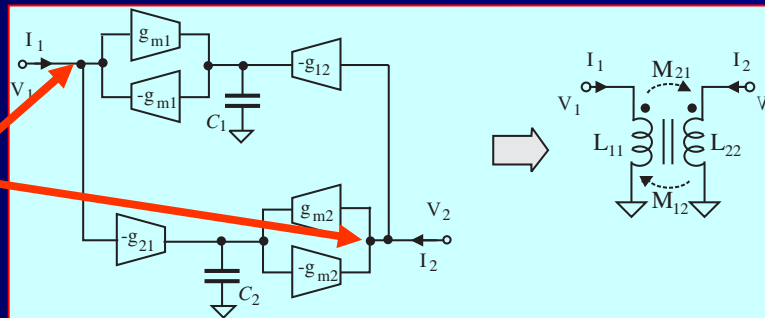


Cascode active inductors

Ideal active transformers

- Consist of two active inductors coupled via transconductors
- Ideal active transformers - only the capacitors of transconductors are considered
- Topology 1 – active inductors are coupled via interface nodes

Interface nodes



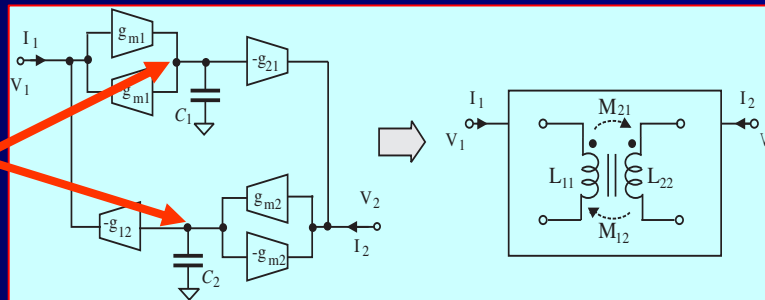
$$L_{11} = \frac{C_1}{g_{m1}^2 \Delta}, \quad M_{12} = \left(\frac{g_{12}}{g_{m1}} \right) \frac{C_2}{g_{m2}^2 \Delta},$$

$$L_{22} = \frac{C_2}{g_{m2}^2 \Delta}, \quad M_{21} = \left(\frac{g_{21}}{g_{m2}} \right) \frac{C_1}{g_{m1}^2 \Delta},$$

where $\Delta = 1 - \frac{g_{12} g_{21}}{g_{m1} g_{m2}}$

- Topology 2 – active inductors are coupled via internal nodes

Internal nodes



$$L_{11} = \frac{C_1}{g_{m1}^2 \Delta}, \quad M_{12} = \left(\frac{g_{12}}{g_{m1}} \right) \frac{C_1}{g_{m1}^2 \Delta},$$

$$L_{22} = \frac{C_2}{g_{m2}^2 \Delta}, \quad M_{21} = \left(\frac{g_{21}}{g_{m1}} \right) \frac{C_2}{g_{m2}^2 \Delta},$$

where $\Delta = 1 - \frac{g_{12} g_{21}}{g_{m1} g_{m2}}$

Ideal active transformers (cont'd)

- Relation between self and mutual inductances

$$M_{12} = \left(\frac{g_{12}}{g_{m1}} \right) L_{22}, \quad M_{21} = \left(\frac{g_{21}}{g_{m2}} \right) L_{11}.$$

- Turn ratio

$$n_{21} = \sqrt{\frac{L_{22}}{L_{11}}} = \left(\frac{g_{m1}}{g_{m2}} \right) \sqrt{\frac{C_2}{C_1}}$$

- Coupling factors

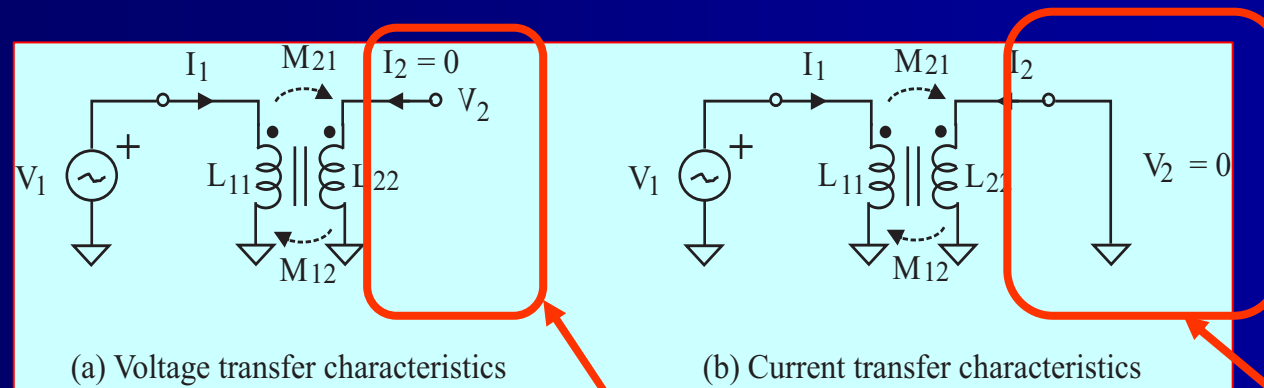
$$k_{21} = \frac{M_{21}}{\sqrt{L_{11}L_{22}}} = \left(\frac{g_{21}}{g_{m1}} \right) \sqrt{\frac{C_1}{C_2}},$$
$$k_{12} = \frac{M_{12}}{\sqrt{L_{11}L_{22}}} = \left(\frac{g_{12}}{g_{m2}} \right) \sqrt{\frac{C_2}{C_1}}.$$

- Impedance transformation

$$Z_{22} = n_{21}^2 Z_{11},$$
$$Z_{12} = \left(\frac{g_{12}}{g_{21}} \right) n_{21} Z_{21}.$$

Ideal active transformers (cont'd)

- Voltage / current transfer characteristics
 - Passive transformers – scaled by turn-ratio only.
 - Active transformers - scaled by both turn-ratio and coupling coefficient.



Open-circuited

Short-circuited

Passive transformers



$$V_2 = n_{21}V_1, \quad I_2 = \frac{I_1}{n_{21}}.$$

Active transformers

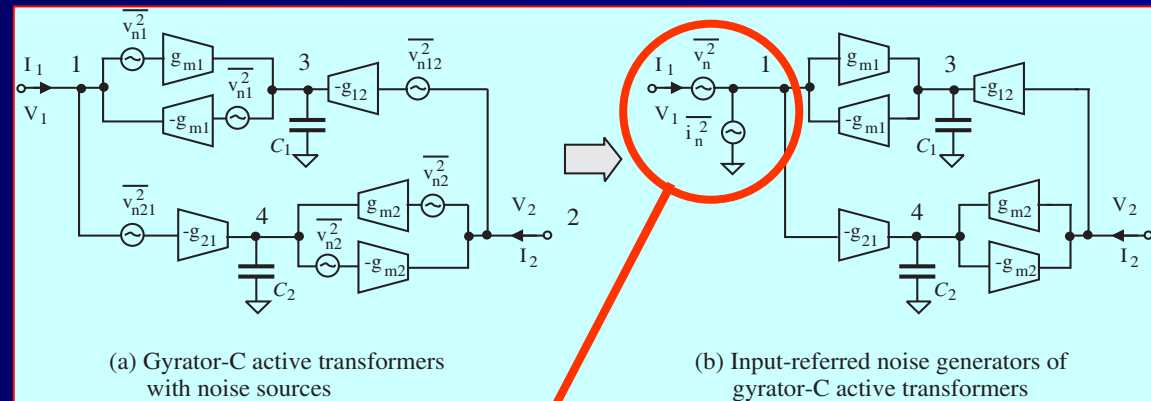


$$V_2 = k_{21}(n_{21}V_1), \quad I_2 = k_{21}\left(\frac{I_1}{n_{21}}\right).$$

Ideal active transformers (cont'd)

■ Noise

- Input-referred noise current generator of trans-conductors is neglected.



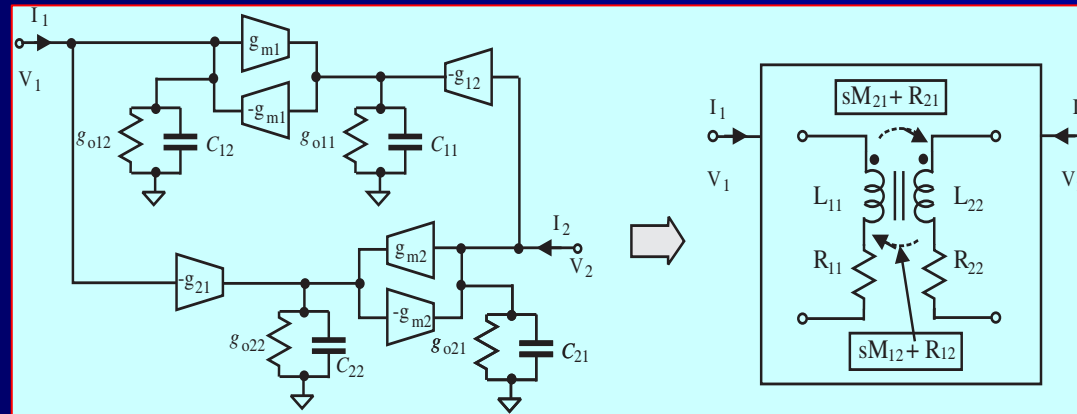
- Input-referred noise voltage & current generators of active transformers

$$\bar{v}_n^2 = \bar{v}_{n21}^2 + \left(\frac{g_{m2}}{g_{21}}\right)^2 \left[1 + \left(\frac{\omega}{\omega_{t2}}\right)^2\right] \bar{v}_{n2}^2,$$

$$\bar{i}_n^2 = \left(\frac{\omega_{t2}}{\omega}\right)^2 \left[\left(\frac{g_{m1}}{g_{m2}}\right)^2 \bar{v}_{n1}^2 + \left(\frac{g_{m1}}{g_{21}}\right)^2 \bar{v}_{n2}^2 + \left(\frac{g_{m1}}{g_{m2}}\right)^2 \bar{v}_{n21}^2 + \left(g_{12} \frac{g_{m1}}{g_{m2}}\right)^2 \bar{v}_{n12}^2 \right]$$

Non-ideal active transformers

- Both capacitance & conductance of transconductors are considered



- Self/mutual inductances and resistances
 - Resistances exist – finite Q.

$$\begin{aligned}
 L_{11} &= \frac{C_{11}}{g_{m1}^2 \Delta}, & R_{11} &= \frac{g_{o11}}{g_{m1}^2 \Delta}, & M_{12} &= \left(\frac{g_{12}}{g_{m1}} \right) \frac{C_{22}}{g_{m2}^2 \Delta}, & R_{12} &= \left(\frac{g_{12}}{g_{m1}} \right) \frac{g_{o22}}{g_{m2}^2 \Delta} \\
 L_{22} &= \frac{C_2}{g_{m2}^2 \Delta}, & R_{22} &= \frac{g_{o22}}{g_{m2}^2 \Delta}, & M_{21} &= \left(\frac{g_{21}}{g_{m2}} \right) \frac{C_{11}}{g_{m1}^2 \Delta}, & R_{21} &= \left(\frac{g_{21}}{g_{m2}} \right) \frac{g_{o11}}{g_{m1}^2 \Delta}
 \end{aligned}$$

Non-ideal active transformers (cont'd)

■ Stability

– Assumptions to simplify analysis:

- $g_{o11}=g_{o12}=g_{o21}=g_{o22}=g_o$
- $g_{m1}=g_{m2}=g_m$
- $g_{12}=g_{21}=g_c$
- $C_{11}=C_{22}=C$

– Characteristic equation



$$s^2 \left(\frac{4g_o^2}{\omega_t^2 g_m^2} \right) + s \left(\frac{4g_o}{\omega_t g_m} \right) + \Delta = 0$$

– Poles are in left s-plane

- Stable



$$s_{1,2} = \frac{\omega_t g_m}{2g_o} \left(-1 \pm \frac{g_c}{g_m} \right)$$

– Frequency range



$$\frac{g_o}{C} < \omega < \left(\frac{g_m}{2g_o} \right) \omega_t, \text{ where } \omega_t = \frac{g_m}{C}$$

– Quality factors

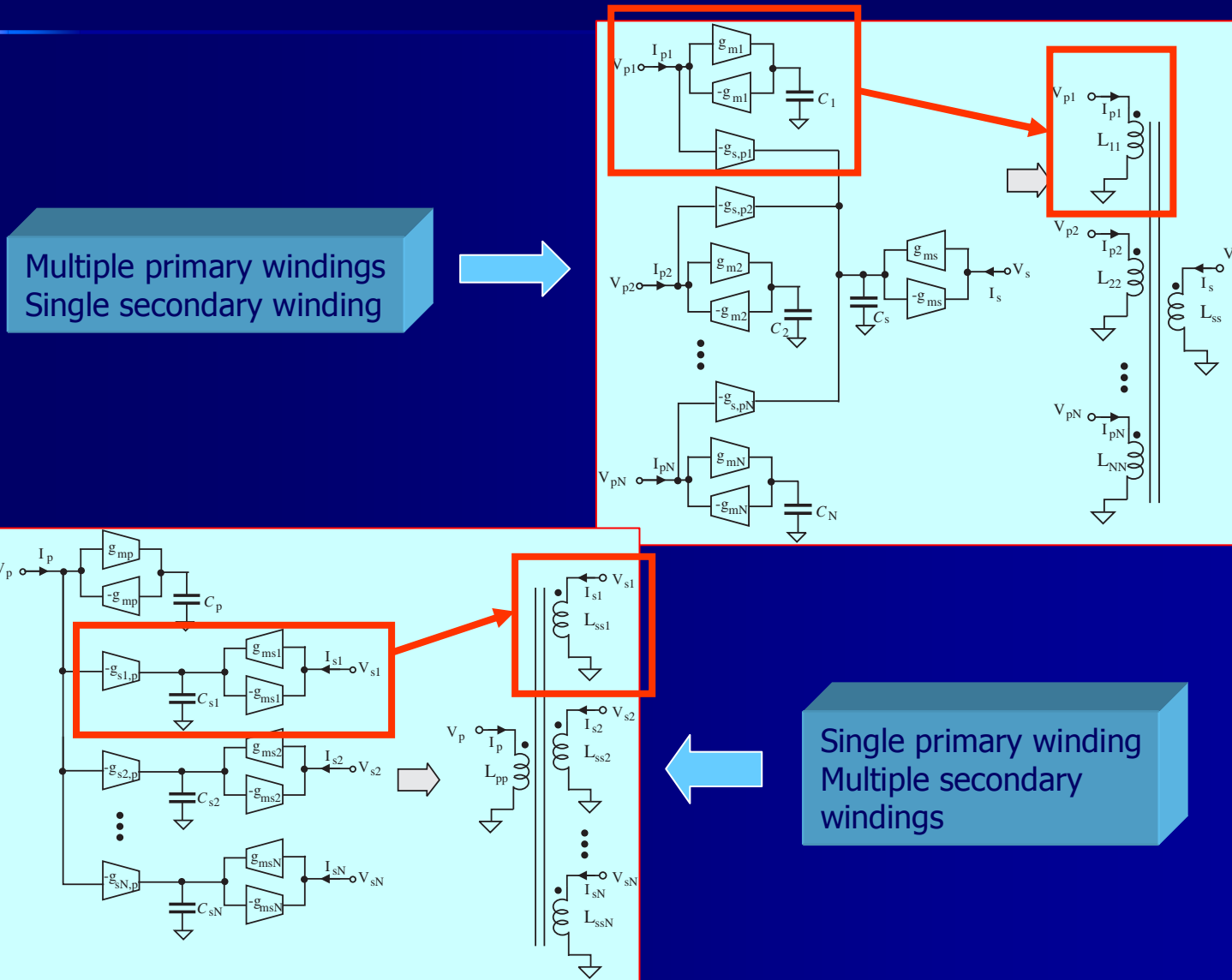
- Self quality factors
- Mutual quality factors



$$Q_{12} = \frac{\omega M_{12}}{R_{12}}, \quad Q_{21} = \frac{\omega M_{21}}{R_{21}},$$

$$Q_{11} = \frac{\omega L_{11}}{R_{11}}, \quad Q_{22} = \frac{\omega L_{22}}{R_{22}},$$

Active transformers with multiple windings

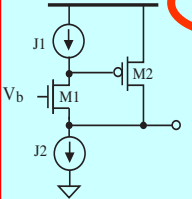
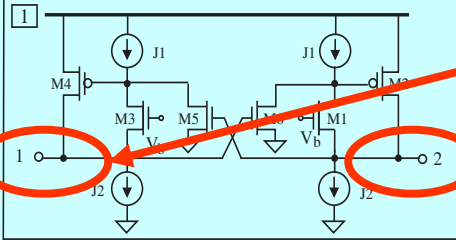
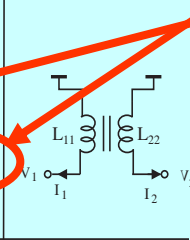
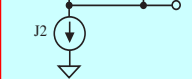
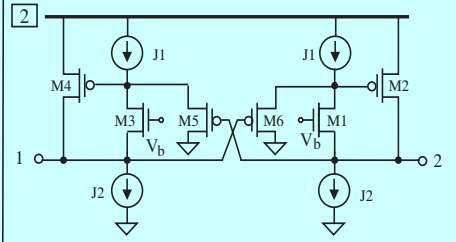
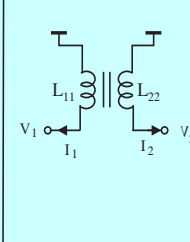
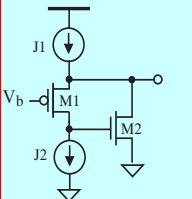
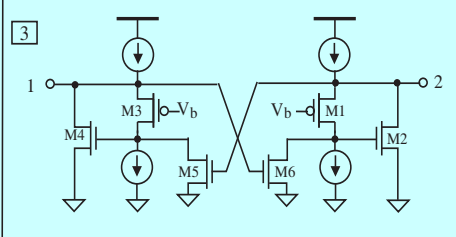
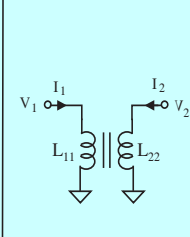

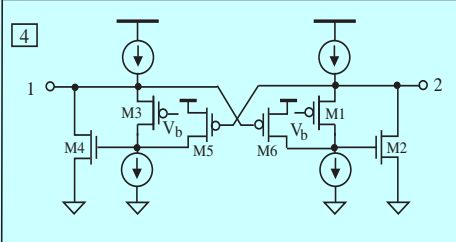
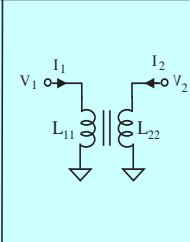


Multiple primary windings
Single secondary winding

Single primary winding
Multiple secondary windings

Implementation of active transformers

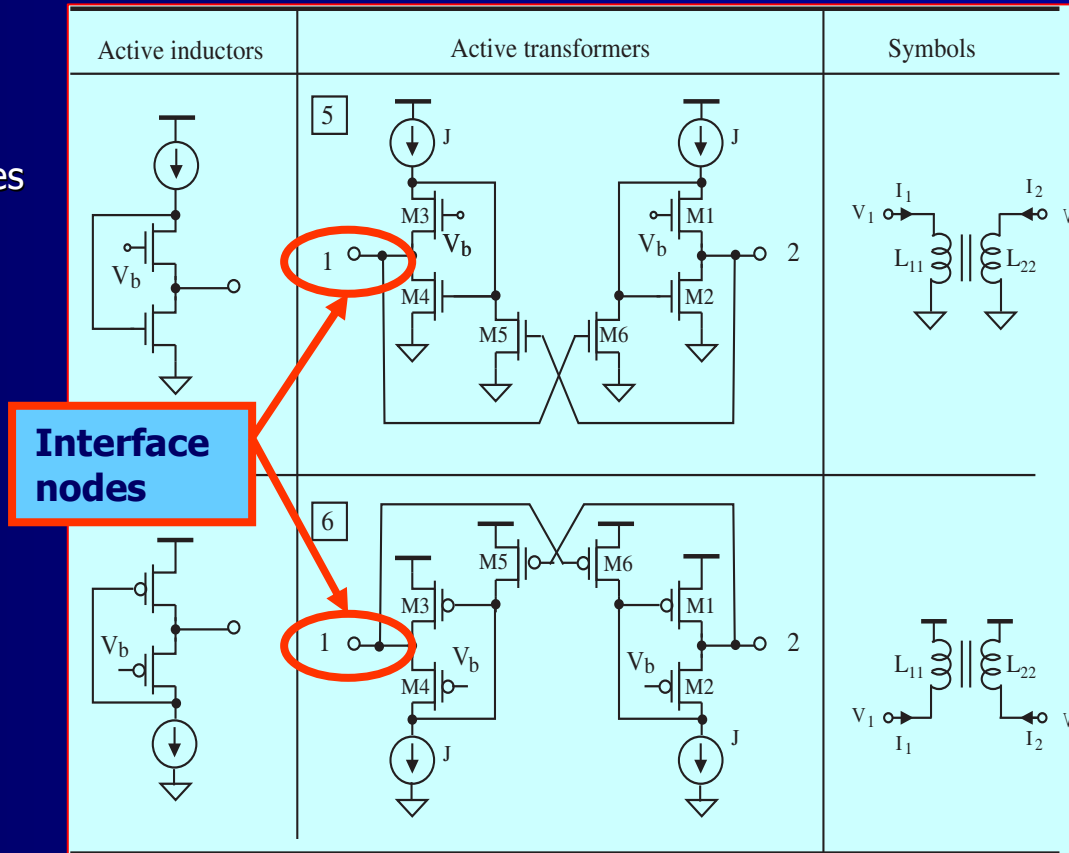
- Class A active transformers
 - coupled via interface nodes

| Active inductors | Active transformers | Symbols |
|--|---|---|
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|  |  |  |
|  |  |  |
|  |  |  |

Interface nodes

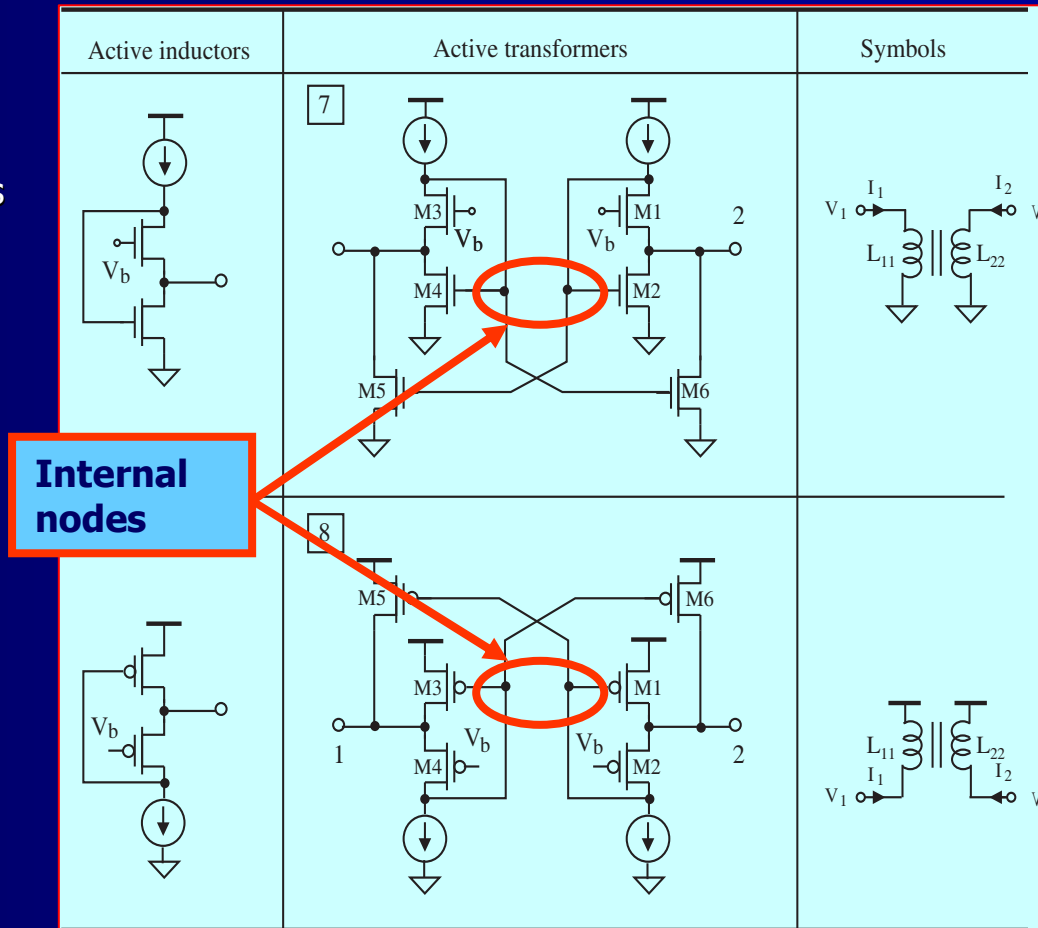
Implementation of active transformers (cont'd)

- Class A active transformers
 - coupled via interface nodes



Implementation of active transformers (cont'd)

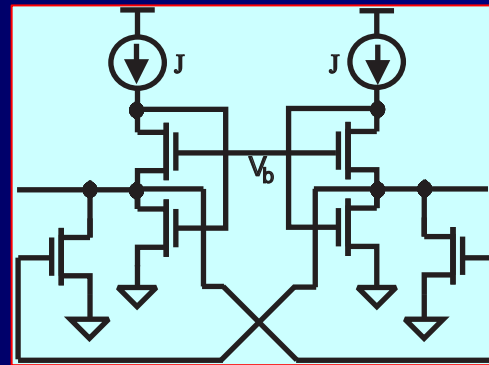
- Class A active transformers
 - coupled via internal nodes



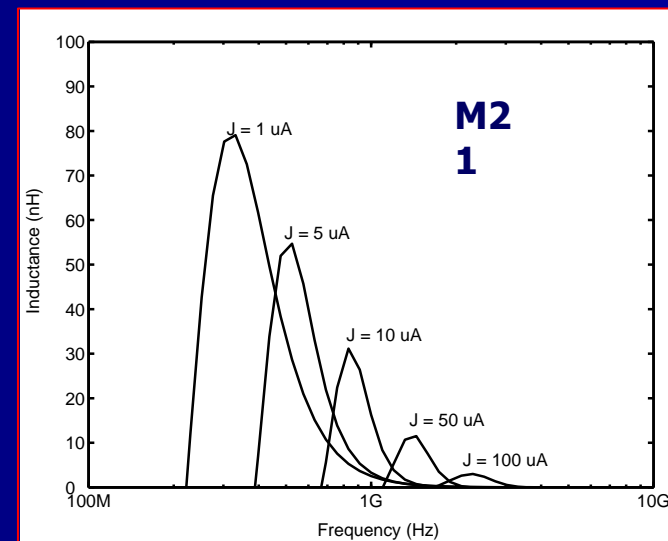
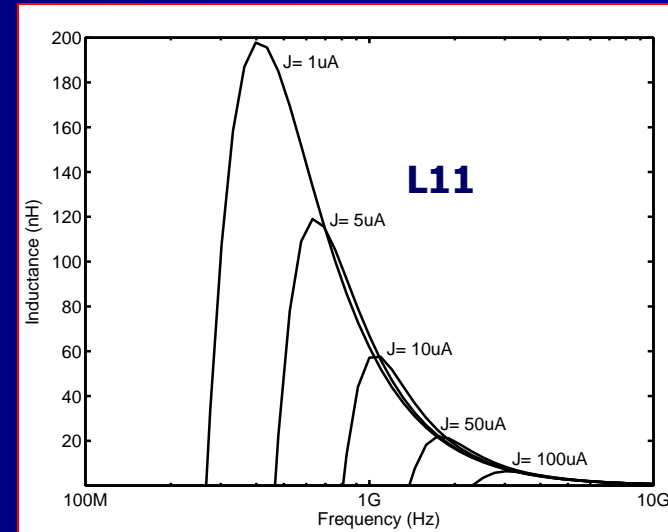
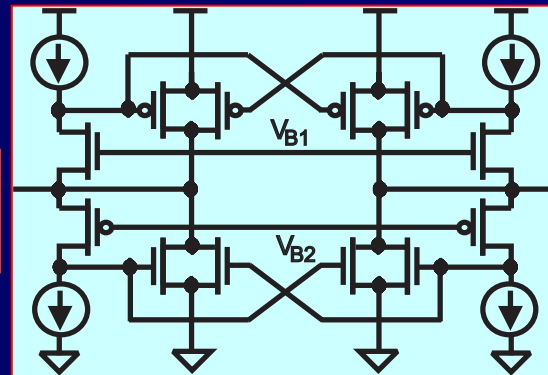
Implementation of active transformers (cont'd)

- Class AB active transformers
 - Improve dynamic range and Q.

Class A

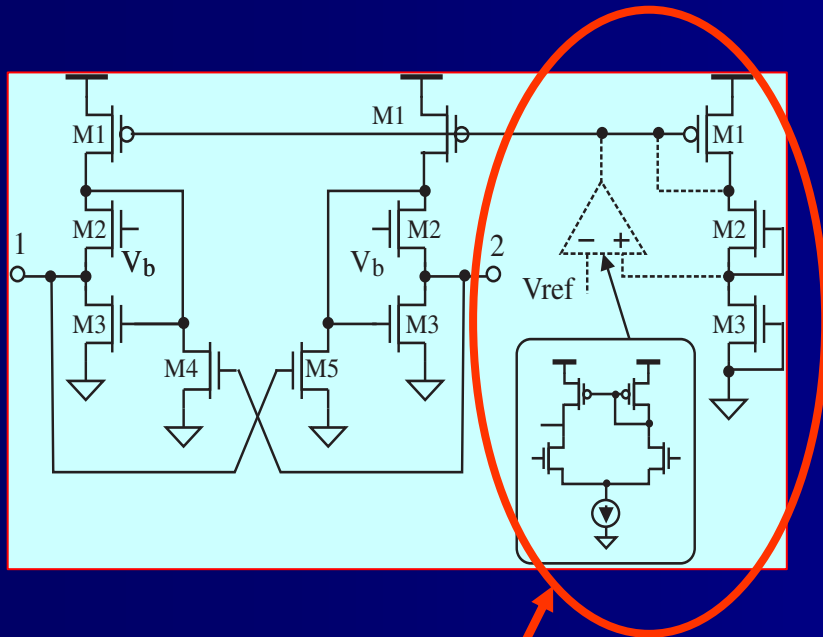


Class AB

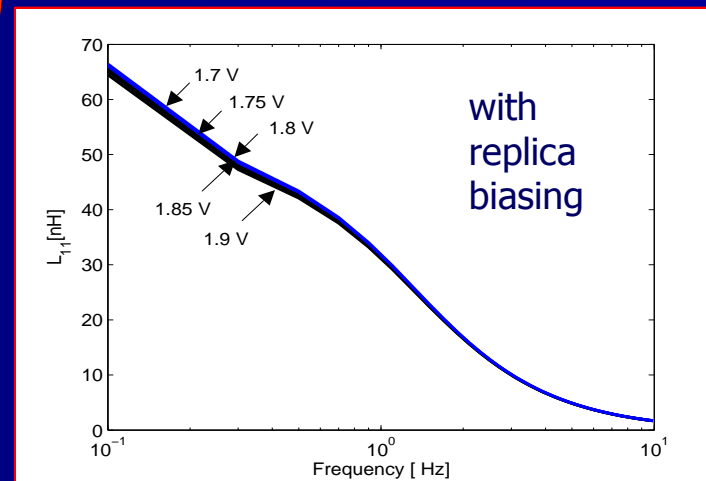
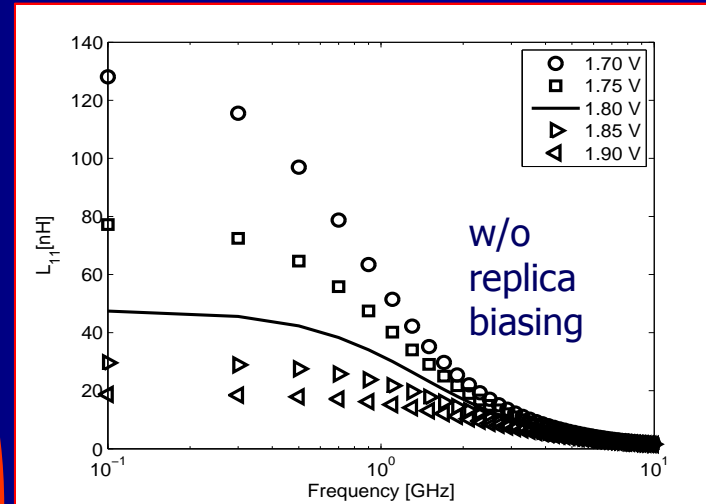


Implementation of active transformers (cont'd)

- Inductances are sensitive to VDD fluctuation
 - Use replica biasing to minimize the effect of VDD fluctuation

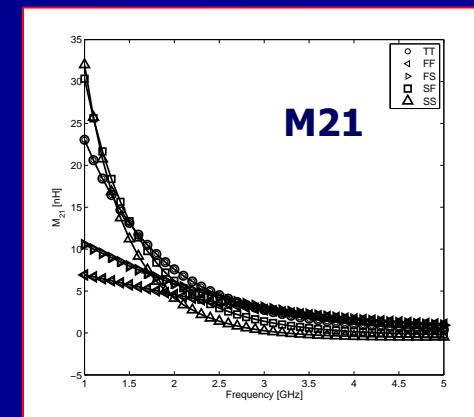
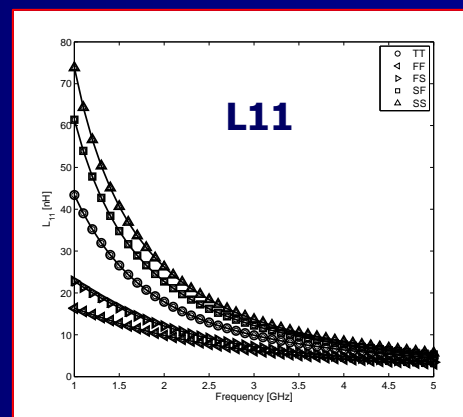
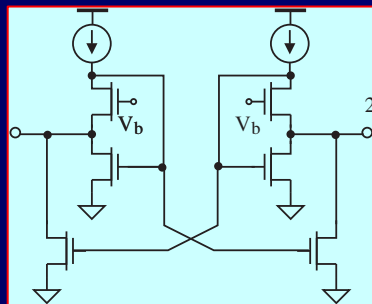
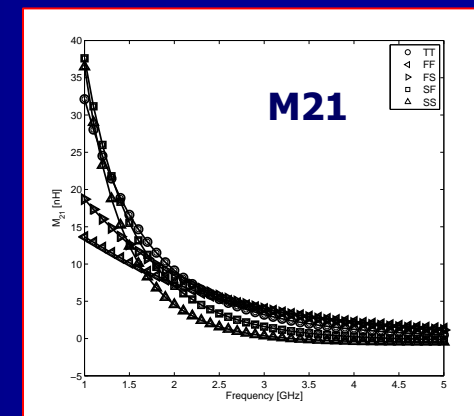
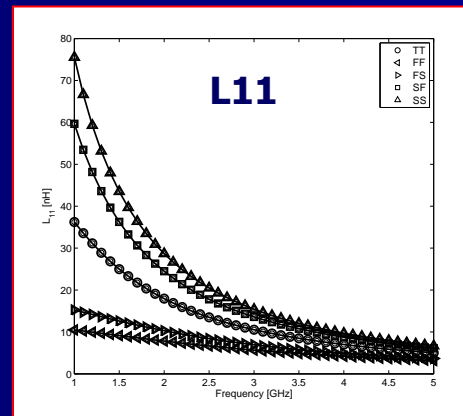
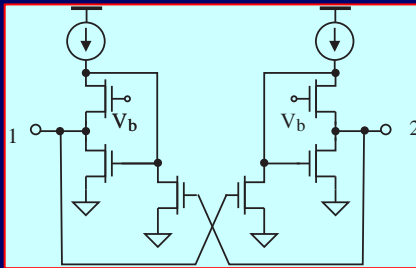


Replica biasing



Implementation of active transformers (cont'd)

- Inductances are sensitive to process variation
 - Self inductances are more sensitive to process variation



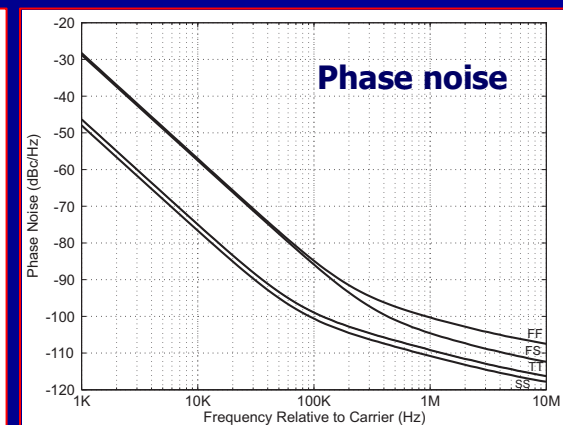
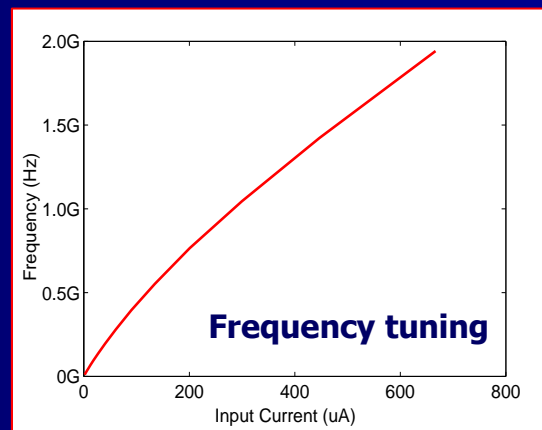
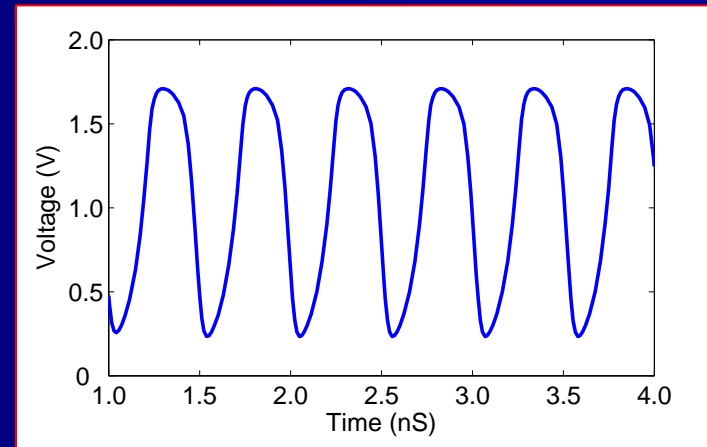
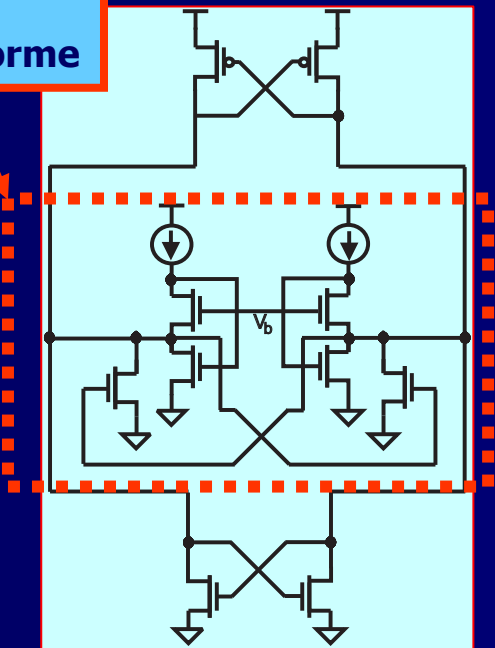
Applications of active transformers

- LC oscillators
- LC quadrature oscillators
- Current-mode phase-locked loops
- QPSK modulators

LC oscillators

- Class A active transformer LC oscillators
 - 1.6 GHz oscillator
 - TSMC-0.18um 1.8V CMOS.
 - Phase noise < -100 dBc/Hz @ 1 MHz frequency offset.

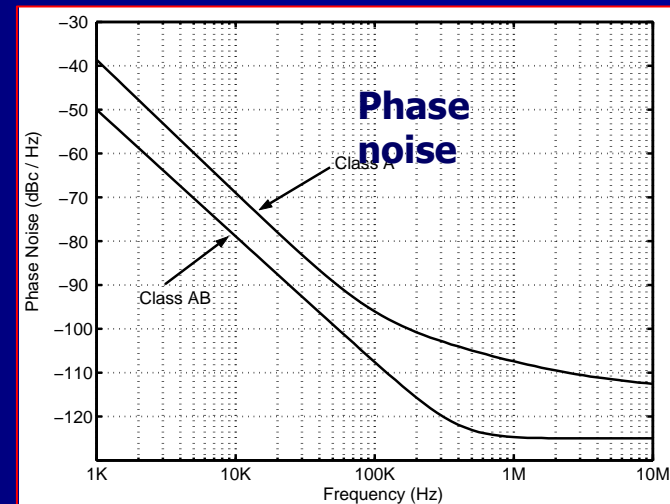
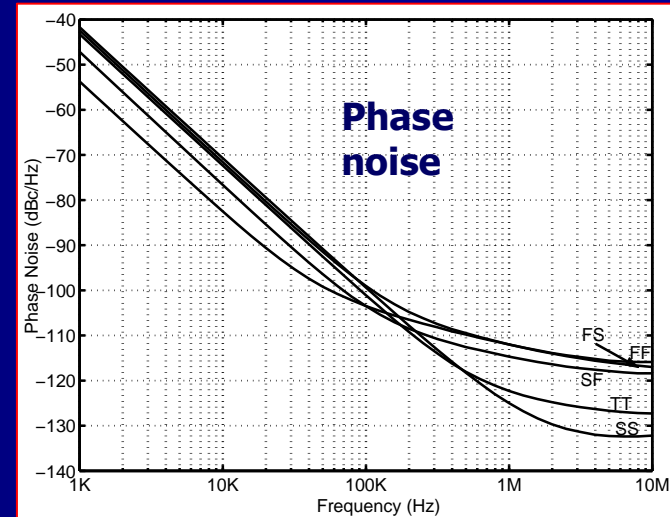
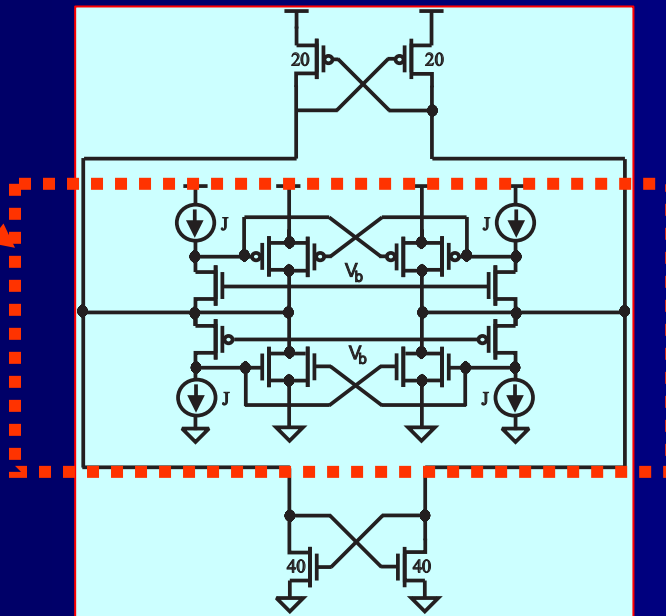
Class A active transformer



LC oscillators (cont'd)

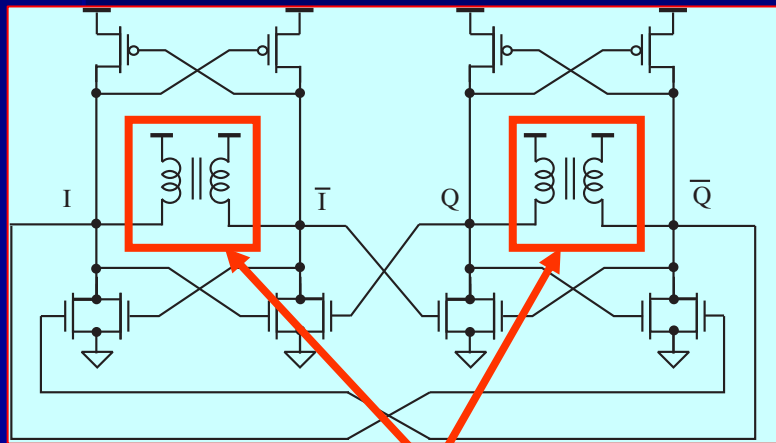
- Class AB active transformer LC oscillators
 - 1.6 GHz oscillator
 - TSMC-0.18um 1.8V CMOS.
 - Phase noise < -110 dBc/Hz @ 1MHz freq. offset.
 - Improved phase noise as compared with class A active transformer LC oscillators

**Class AB
active
transformer**

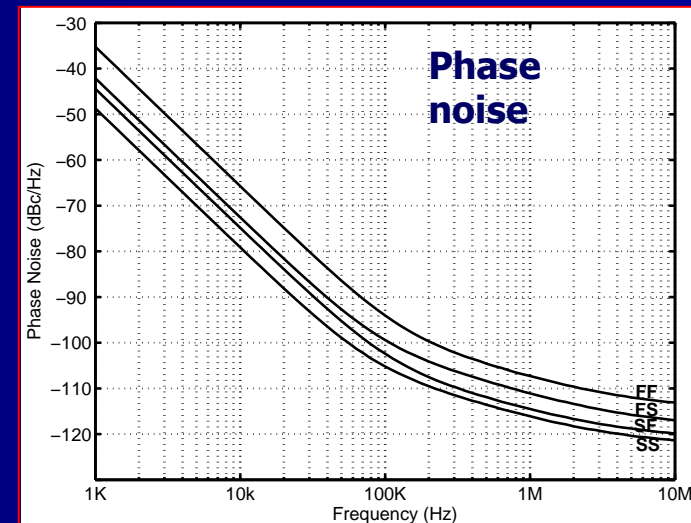
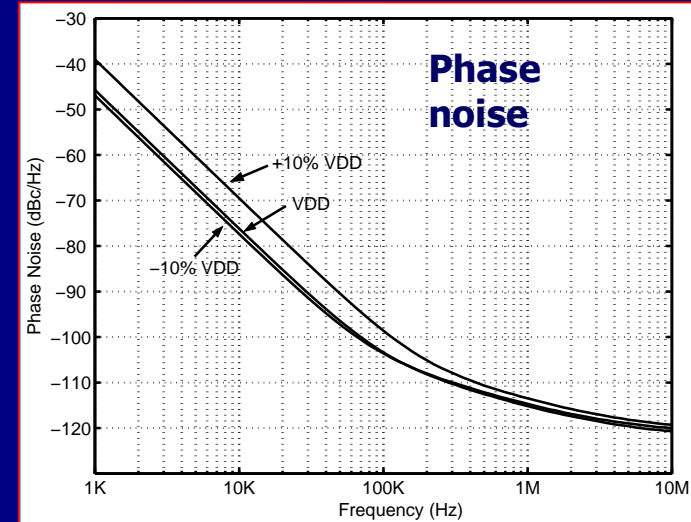


LC quadrature oscillators

- The same configuration as quadrature with passive transformers
 - 1.6 GHz oscillator
 - TSMC-0.18um 1.8V CMOS.
 - Phase noise < -110 dBc/Hz @ 1MHz freq. offset.

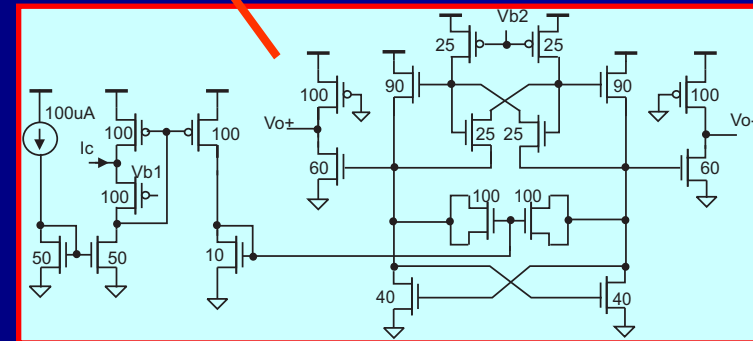
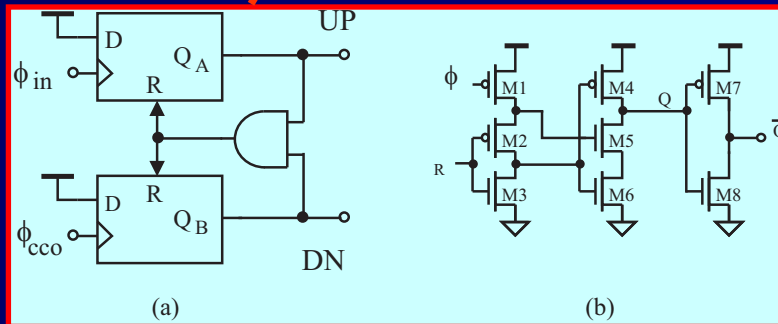
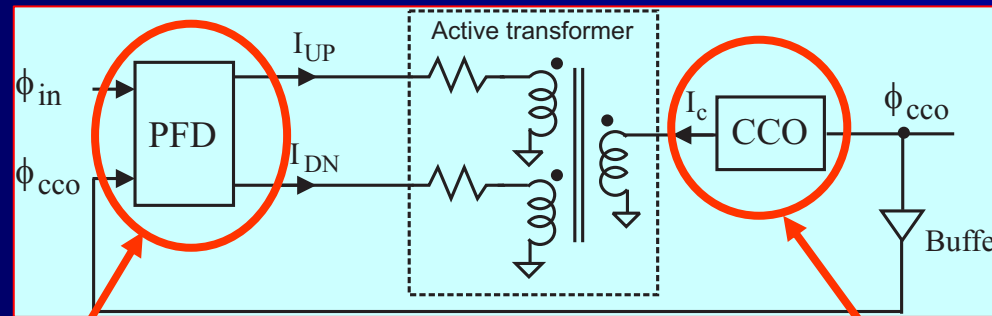


Active



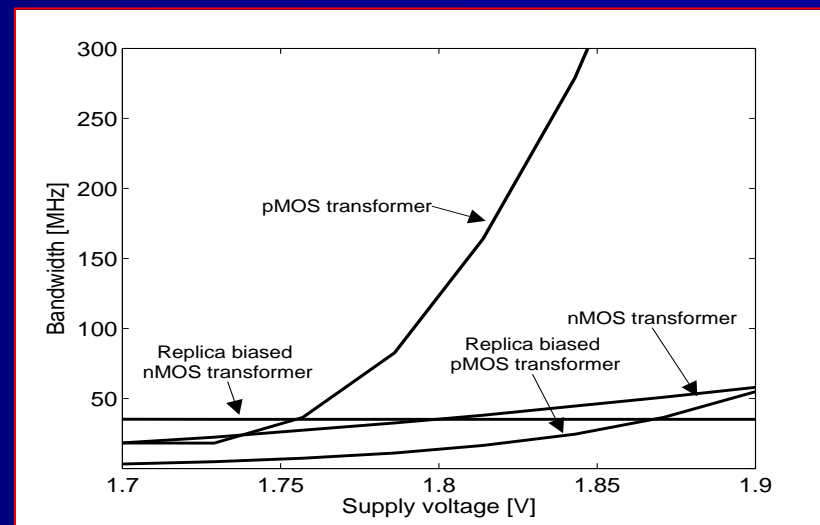
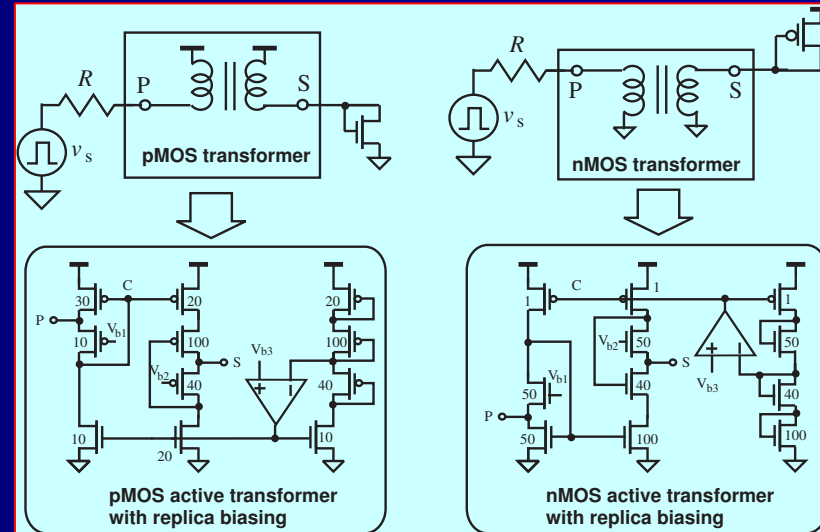
Current-mode PLLs

- Current-mode PLLs
 - Voltage-mode loop filters – voltage output to control downstream VCO.
 - Current-mode loop filters – current output to control downstream CCO.

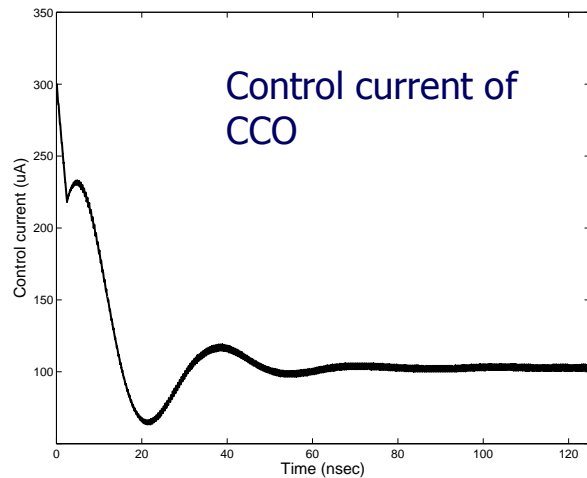


Current-mode PLLs (cont'd)

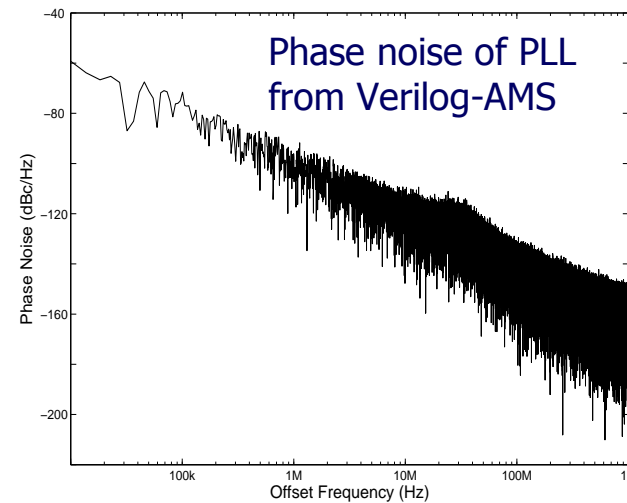
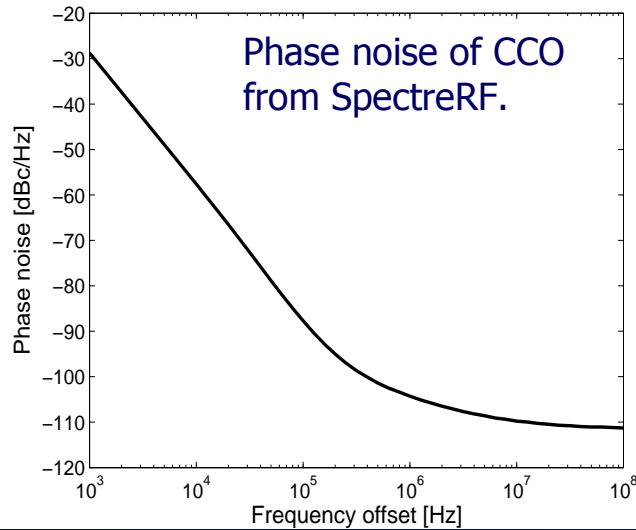
- Sensitivity of current-mode loop filter to VDD fluctuation
 - nMOS active transformers are less sensitive to VDD fluctuation as compared with pMOS active transformers.
 - Replica biasing is effective in reducing sensitivity to VDD fluctuation



Current-mode PLLs (cont'd)

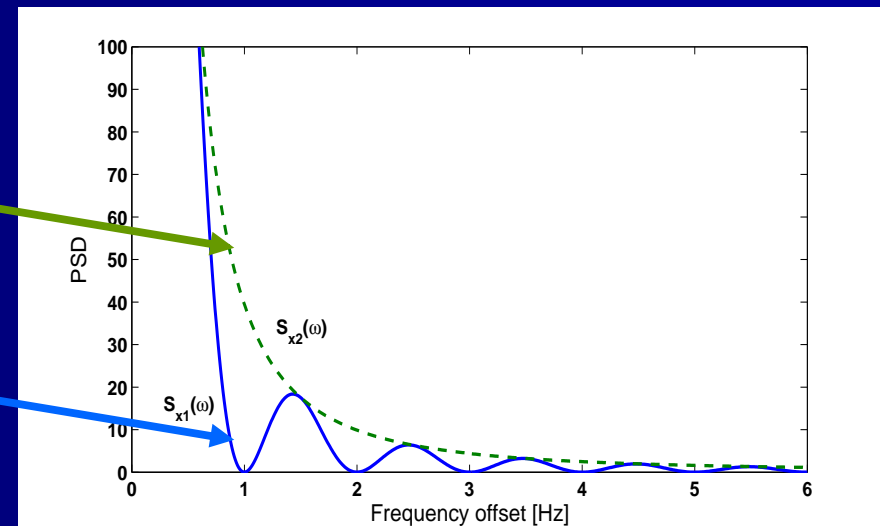
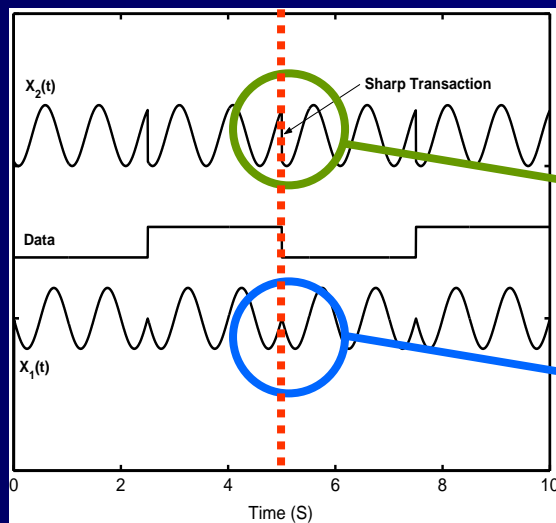


Lock time : 60 ns
Phase noise of CCO : < -100 dBc/Hz
@ 1 MHz freq. offset.
Phase noise of PLL : < -100 dBc/Hz
@ 1 MHz freq. offset.
Phase noise of PLL is dominated by that of CCO.



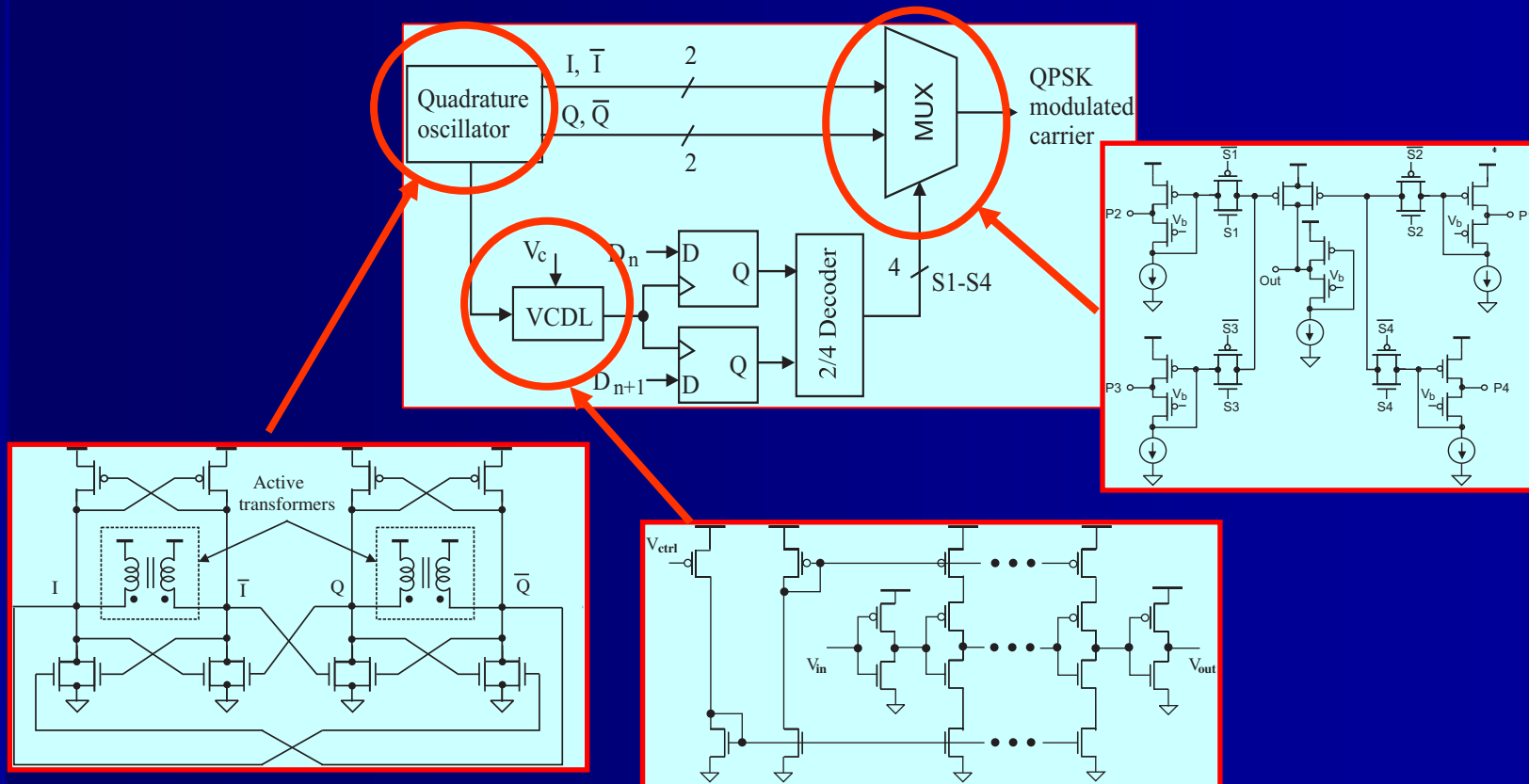
QPSK modulators

- Minimize bandwidth of modulated signals
 - Modulating at peaks – large bandwidth
 - Modulating at zero-crossings – small bandwidth

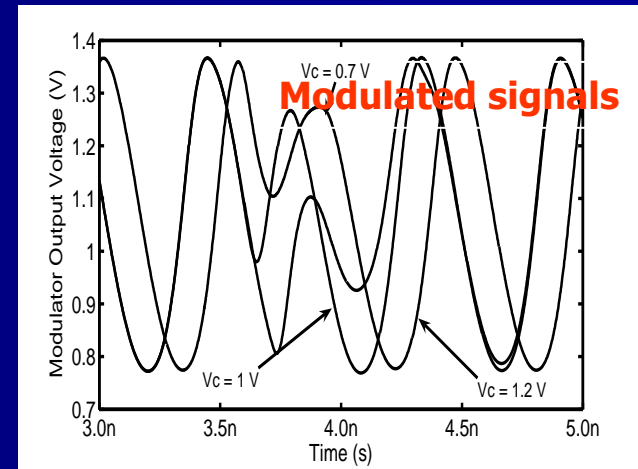
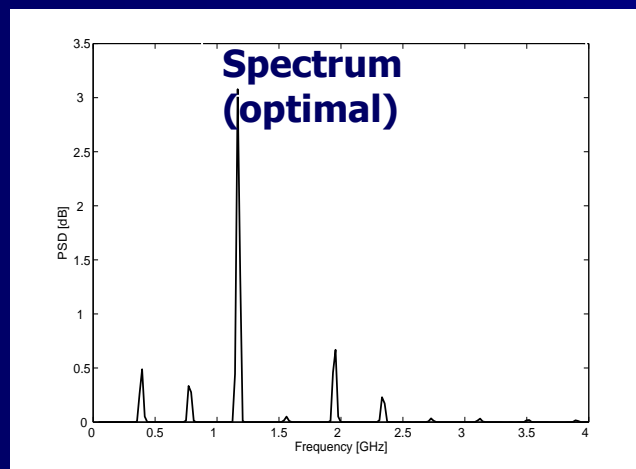
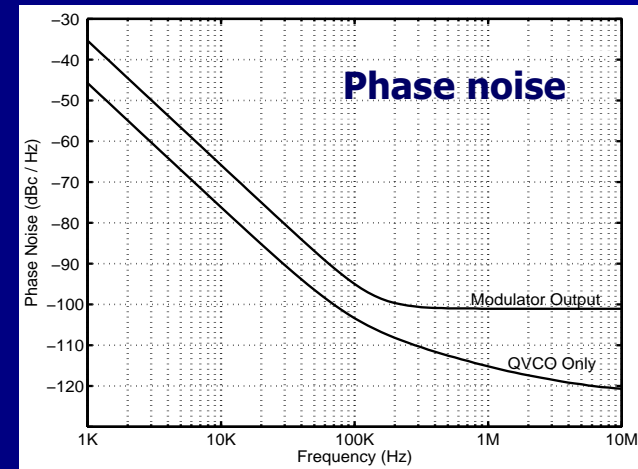
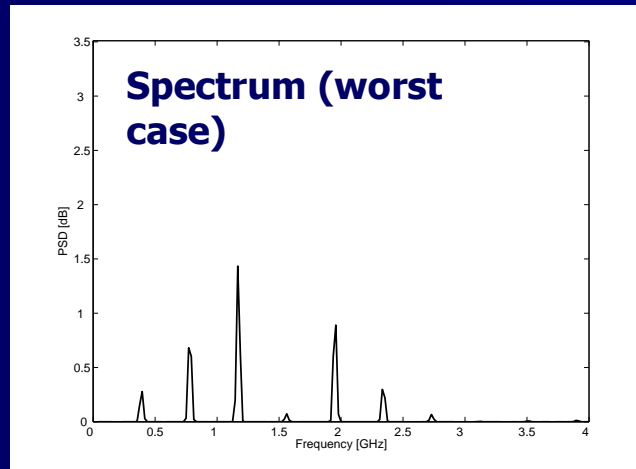


QPSK modulators (cont'd)

- Active transformer quadrature oscillator generates quadrature signals.
- VCDL provides the optimal modulating points



QPSK modulators (cont'd)



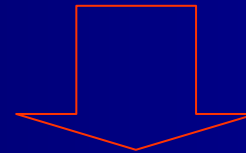
Conclusions

Advantages:

- Little silicon requirement
- Tunable self and mutual inductances
- Large Q achievable
- Fully realizable in digital CMOS technologies
- Good noise performance when noise-shaping techniques (high-Q and sigma-delta modulation) are used.
- Good dynamic range
 - gyrator-C is inductive even when devices are in triode

Disadvantages:

- Poor noise performance for wideband applications
- DC power consumption
- Inductances are frequency-dependent
- Sensitive to VDD fluctuation
- Sensitive to process variation



Conclusions:

- An economical way to build VCOs, especially quadrature VCOs.
- Improved phase noise with noise-shaping techniques.

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Thank